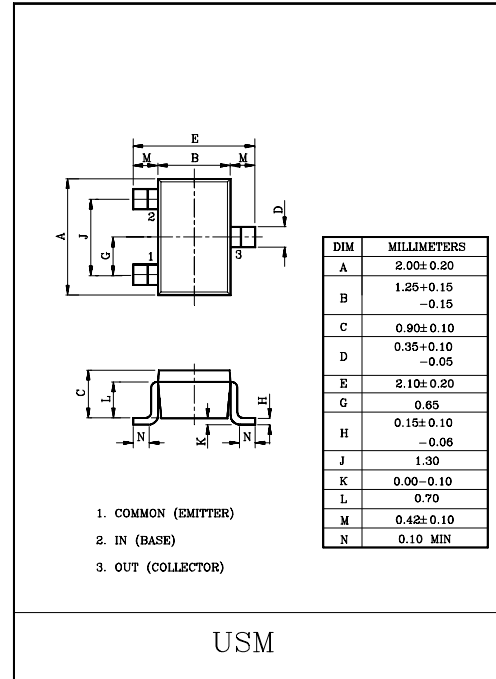
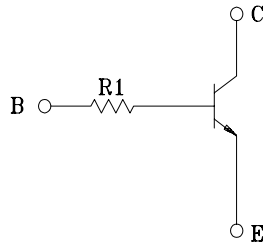


SWITCHING APPLICATION.
INTERFACE CIRCUIT AND DRIVER CIRCUIT APPLICATION.

FEATURES

- With Built-in Bias Resistors.
- Simplify Circuit Design.
- Reduce a Quantity of Parts and Manufacturing Process.
- High Packing Density.

EQUIVALENT CIRCUIT



MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	5	V
Collector Current	I _C	100	mA

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector Power Dissipation	P _C	100	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	-55~150	°C

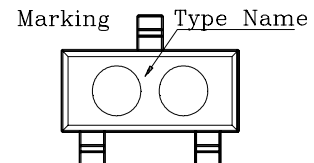
ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Collector Cut-off Current	I _{CBO}	V _{CB} =50V, I _E =0	-	-	100	nA	
Emitter Cut-off Current	I _{EBO}	V _{EB} =5V, I _C =0	-	-	100	nA	
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =1mA	120	-	-		
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =10mA, I _B =0.5mA	-	0.1	0.3	V	
Transition Frequency	f _T *	V _{CE} =10V, I _C =5mA	-	250	-	MHz	
Input Resistor	KRC410	R _i		-	4.7	-	kΩ
	KRC411			-	10	-	
	KRC412			-	100	-	
	KRC413			-	22	-	
	KRC414			-	47	-	

Note : * Characteristic of Transistor Only

MARK SPEC

TYPE	KRC410	KRC411	KRC412	KRC413	KRC414
MARK	NK	NM	NN	NO	NP



KRC410~KRC414

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Switching Time	Rise Time	KRC410	V _O =5V V _{IN} =5V R _L =1kΩ	-	0.025	-	μS
		KRC411		-	0.03	-	
		KRC412		-	0.3	-	
		KRC413		-	0.06	-	
		KRC414		-	0.11	-	
	Storage Time	KRC410		-	3.0	-	
		KRC411		-	2.0	-	
		KRC412		-	6.0	-	
		KRC413		-	4.0	-	
		KRC414		-	5.0	-	
	Fall Time	KRC410		-	0.2	-	
		KRC411		-	0.12	-	
		KRC412		-	2.0	-	
		KRC413		-	0.9	-	
		KRC414		-	1.4	-	